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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR

2SK3432

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3432 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

• Super low on-state resistance:

 $R_{DS(on)1}$ = 4.0 $m\Omega$ MAX. (Vgs = 10 V, ID = 42 A)

 $R_{DS(on)2} = 6.9 \text{ m}\Omega$ MAX. (Vgs = 4 V, ID = 42 A)

- Low Ciss: Ciss = 9500 pF TYP.
- Built-in gate protection diode

ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK3432	TO-220AB		
2SK3432-S	TO-262		
2SK3432-ZJ	TO-263		
2SK3432-Z	TO-220SMD ^{Note}		

Note TO-220SMD package is produced only in Japan.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	40	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	±83	Α
Drain Current (pulse) Note1	ID(pulse)	±332	Α
Total Power Dissipation (Tc = 25°C)	Рт	100	W
Total Power Dissipation (T _A = 25°C)	Pτ	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	IAS	69	Α
Single Avalanche Energy Note2	Eas	476	mJ

Notes 1. PW \leq 10 μ s, Duty cycle \leq 1%

2. Starting Tch = 25°C, VDD = 20 V, Rg = 25 Ω , Vgs = 20 \rightarrow 0 V

(TO-220AB)



(TO-262)



(TO-263, TO-220SMD)



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ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 40 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	lgss	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	٧
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 42 A	40	80		S
Drain to Source On-state Resistance	RDS(on)1	V _{GS} = 10 V, I _D = 42 A		3.2	4.0	mΩ
	RDS(on)2	V _{GS} = 4 V, I _D = 42 A		4.8	6.9	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		9500		pF
Output Capacitance	Coss	V _{GS} = 0 V		2200		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		920		pF
Turn-on Delay Time	td(on)	V _{DD} = 20 V, I _D = 42 A		140		ns
Rise Time	tr	V _{GS} = 10 V	.(1800		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		470		ns
Fall Time	tf			410		ns
Total Gate Charge	Qg	V _{DD} = 32 V		150		nC
Gate to Source Charge	Qgs	V _{GS} = 10 V		29		nC
Gate to Drain Charge	Q _{GD}	ID = 83 A		45		nC
Body Diode Forward Voltage	V _{F(S-D)}	IF = 83 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 83 A, Vgs = 0 V		69		ns
Reverse Recovery Charge	Qrr	$di/dt = 100 A/\mu s$		130		nC

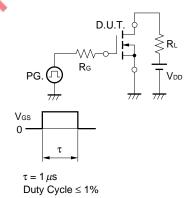
TEST CIRCUIT 1 AVALANCHE CAPABILITY

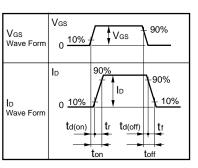
$V_{GS} = 20 \rightarrow 0 \text{ V}$ $V_{GS} = 20 \rightarrow 0 \text{ V}$ V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD}



Starting Tch

TEST CIRCUIT 2 SWITCHING TIME

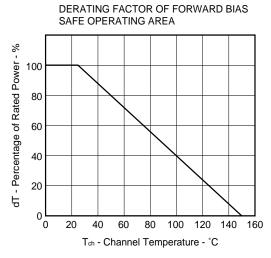




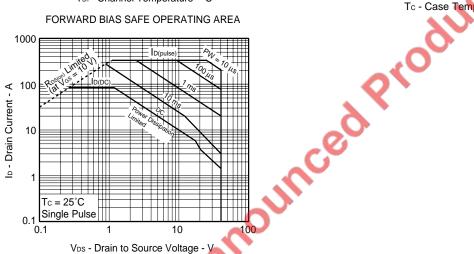
TEST CIRCUIT 3 GATE CHARGE



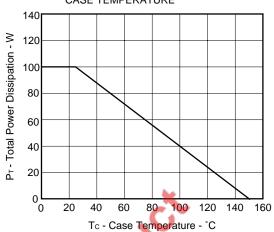
TYPICAL CHARACTERISTICS (TA = 25°C)



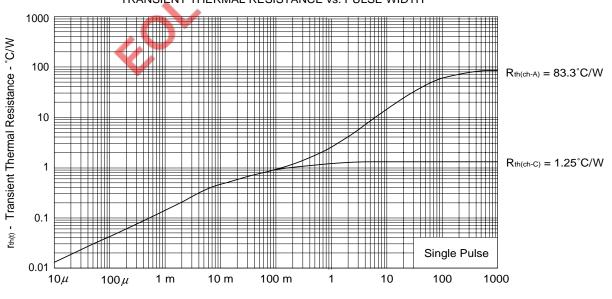
FORWARD BIAS SAFE OPERATING AREA



TOTAL POWER DISSIPATION vs. CASE TEMPERATURE 140

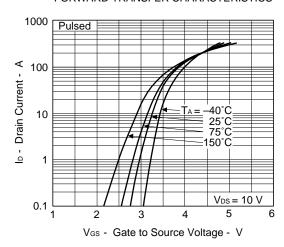


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

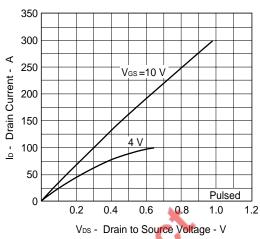


PW - Pulse Width - s

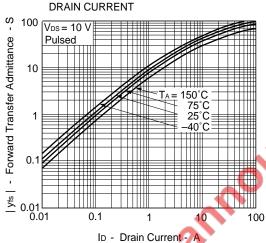
FORWARD TRANSFER CHARACTERISTICS



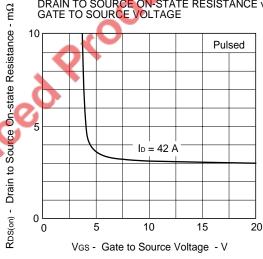
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



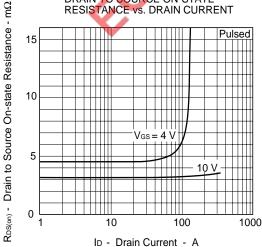
FORWARD TRANSFER ADMITTANCE vs.



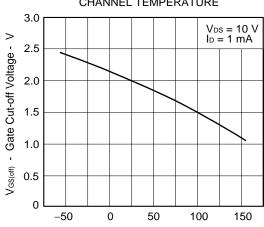
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

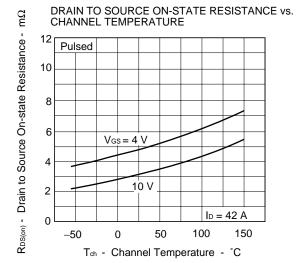


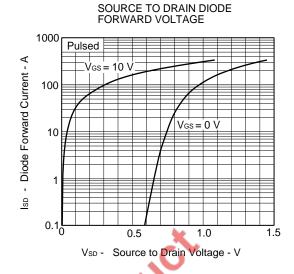
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

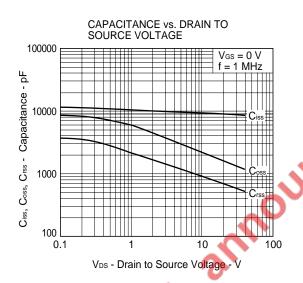


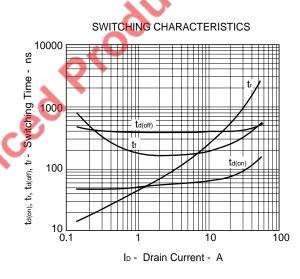
Tch - Channel Temperature - °C

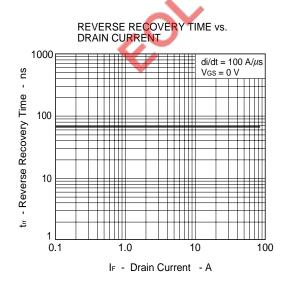


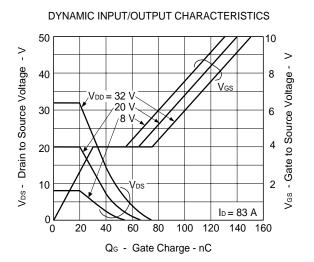


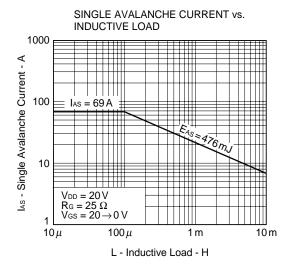


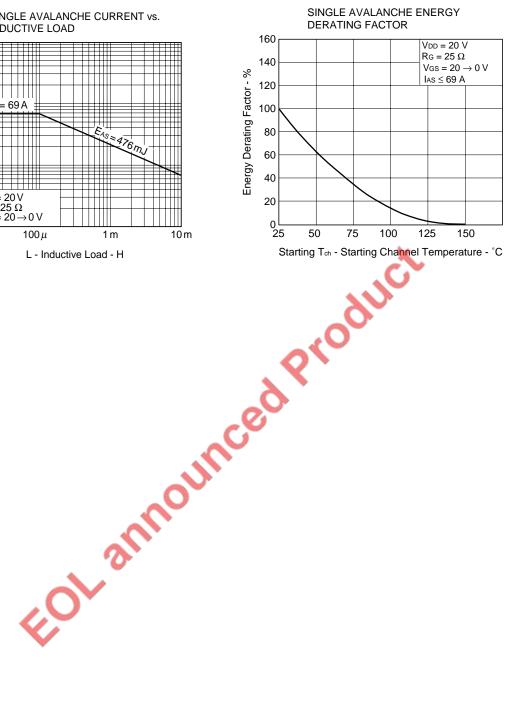








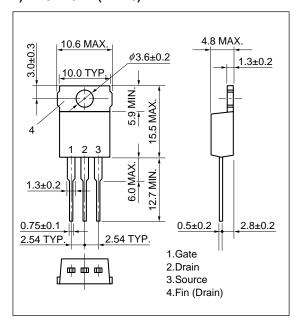




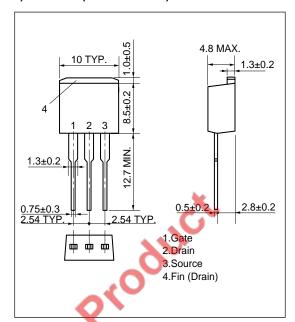


★ PACKAGE DRAWINGS (Unit: mm)

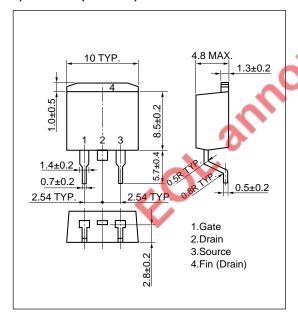
1) TO-220AB (MP-25)



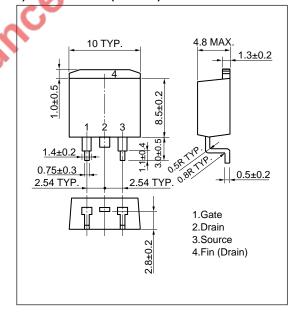
2) TO-262 (MP-25 Fin Cut)



3) TO-263 (MP-25ZJ)

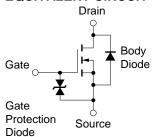


4) TO-220SMD (MP-25Z) Note



Note This package is produced only in Japan.

EQUIVALENT CIRCUIT



Remark

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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